

Radio Frequency sensors & lab-on-chip technologies: news opportunities for biomedical diagnosis

WF-02 Recent Advances in Topologies, Technologies and Practical Realizations of Microwave Sensors



A. Pothier¹,

C. Dalmay¹, D. Cordeau¹,

M. Babay¹, T. Provent¹,

R. Manczak¹, S. Saada²

B. Bessette², F. Lalloue²,

C. Merla³, M. Mancuso³,

M. Tanori³, A. Casciati³,

E. Porcù⁴, E. Rampazzo⁴,

L. Persano⁴, G.Viola⁴,

C. Palego⁵,

E.C Durmaz⁶, C.B Kayank⁶ and M. Kaynak⁶











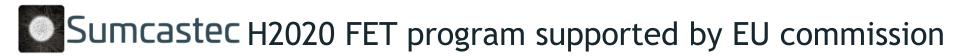
Introduction



- Objectives of the SUMCASTEC Project
- Motivation
- Cell dielectric spectroscopy as a new analysis approach in the microwave spectrum
- Toward New generation of lab on chip with imbedded CMOS electronics?
- Sensing system based on Injection Lock Oscillator architecture
- Measurement and few ppm sensing capability demonstration
- Conclusion

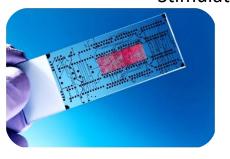
The SUMCASTEC project





New Generation of Microwave Lab-on-Chip for Cancerous
Stem Cells Neutralization using Electromagnetic Waves
Stimulation

<u>Concept:</u> Exploit the non-thermal effects of <u>EM</u> radiations on living organizes to <u>sense</u> and <u>stimulate</u> specifically targeted biological cells





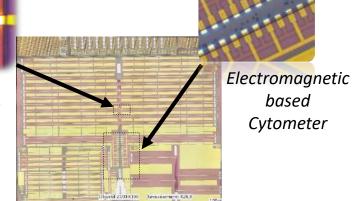


Individual Cell sensor

Methodology: Take benefit of

-Microsystem technologies to individually treat cells on a dedicated Lab-on-Chip (LOC)

-CMOS technology to implement required microwave sources, sensors, applicators and detectors on the same chip



Prototype of microfluidic sensing platform on CMOS chip

15 January 2021

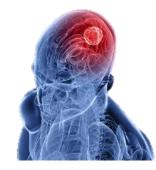
Motivation: Handling pathology with high recurrence



Need for new therapeutic strategies dedicated to poor outcome diseases

Ex: Meduloblastoma ,
Glioblastoma:

- ► Tumor with high recurrence
- ► Strong resistance to existing treatments
- ► Highly heterogeneous brain tumors



Resulting efficiency from standard therapies is very low



Role of some hidden tumor-initiating cells?

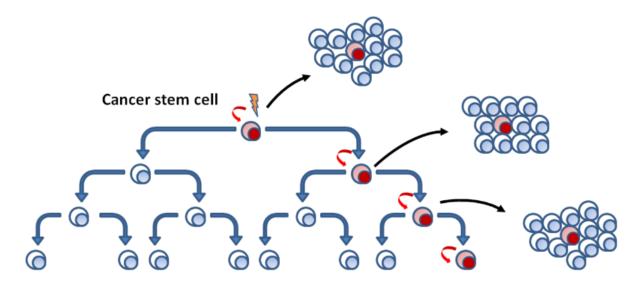
How fight them more efficiently?
How many are they?
Where are they?

Cancerous Stem Cells



Tumorigenic cells with ability to give rise to all tumor cell types:

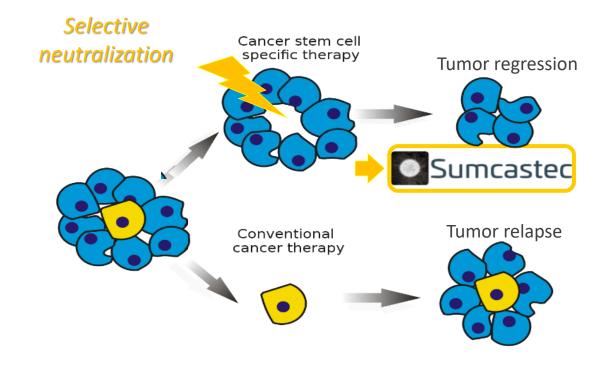
- ▶ with self-renewal capabilities
- ▶ differentiation into multiple cell types (progenitors...)
- ▶ hypothesized to be the main cause of relapse and metastasis



New therapies targeting CSCs



Quiescent properties -> Resistant to conventional chemo and ionizing treatments :



Why CMOS technology?



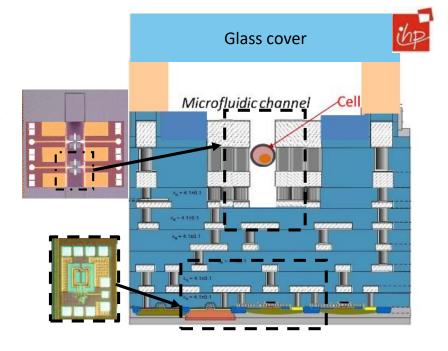
Advantages of BiCMOS technology:

✓ Complete system integration with several electronic functions on the same chip



► <u>Mature technology able to</u> quickly address a large market





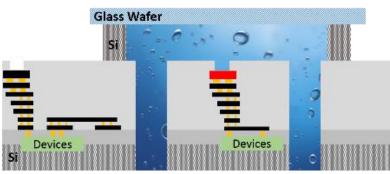
Why CMOS technology?

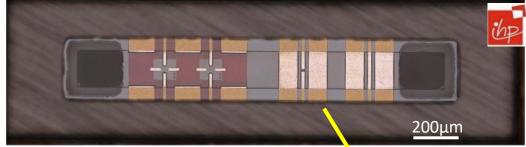


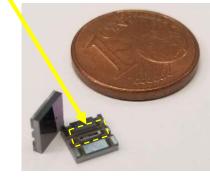
Advantages of BiCMOS technology:

- ✓ Complete system integration with several electronic functions on the same chip
- ✓ Miniaturization of the complete device and Lab-On-Chip compatible

► <u>Full and monolithic integration of</u> microfluidic





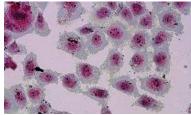


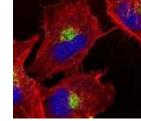
How biologists study CSC's currently?





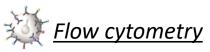
Optical microscopy





Staining

Fluorescence labeling







QPCR & Protein Array analysis

Main difficulties:

- CSC's are rare and require amplification of population
- Specific immunostaining markers are lacking



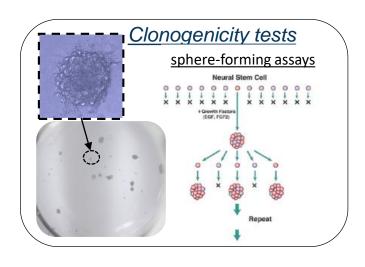
Stemness lineament are accessed using *generic markers* of normal stem cells:

- Undifferentiation & Anti proliferation markers: Nanog, Sox2, OCT4, CD133...
- Cross coupling of makers gives evidence but without 100% absolute certainty

Functional tests allow to identify CSC

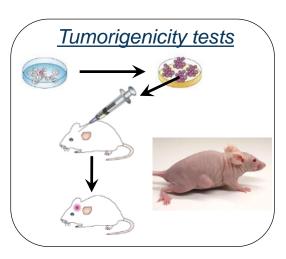


Functional tests prove ability to renew a tumor mass



But.... long (~20-40 days), costly and complex tests to implement

-> Never used in clinic...





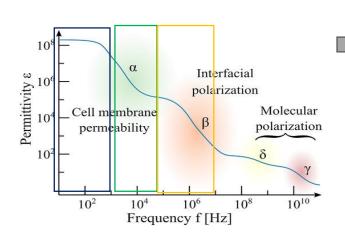
Interest to develop others approaches investigating intracellular specificities

What about using EM field to identify CSC's?

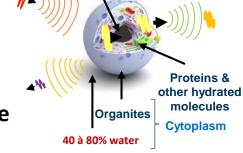


Depending the <u>frequency</u> EM field <u>could</u> interact with different cell constituents

- ➤ Low frequency -> Cell shape/ morphology/size influence
 - ➤ Mid frequency -> Plasma Membrane specificities
 - ➤ High frequency -> Intracellular content properties



Own cell dielectric properties = A signature that can be specific



High frequency signal well suitable to access to cell interior properties and measure specificities

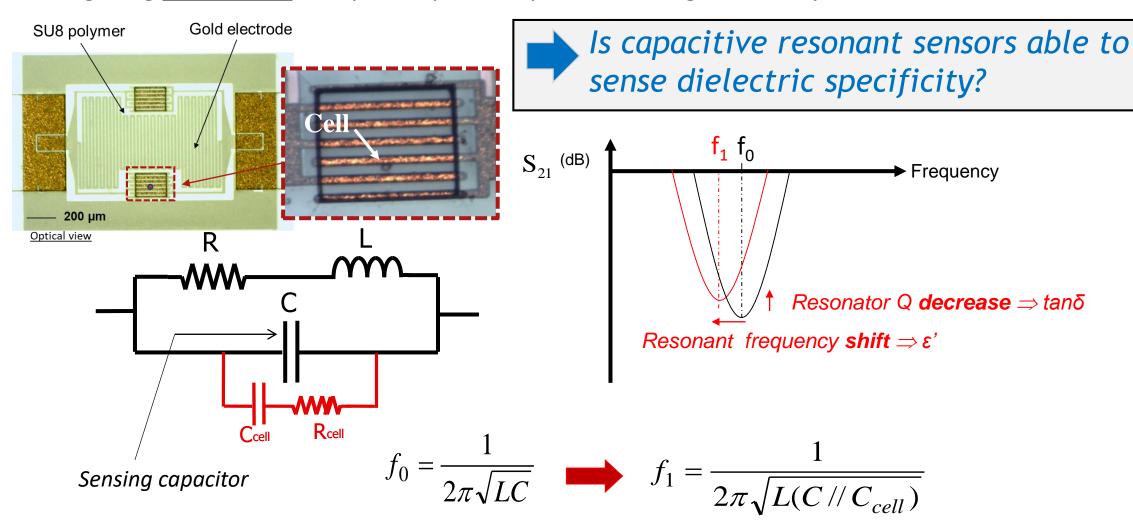


Dielectric spectroscopy allows **non destructive** & **label free** characterization

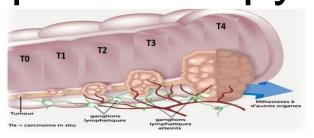
Resonant RF-sensors can be good sensor candidates



Targeting unique cell analysis requires superior sensing sensitivity

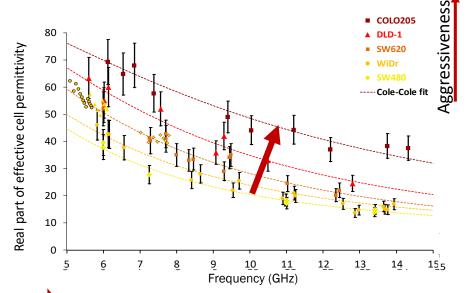


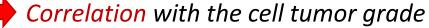
Discriminating cells with dielectric spectroscopy

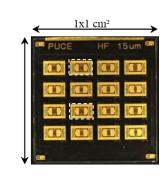


Cell Line	Stage	Morphology
WiDr	II	
SW480	II	1
SW620	III	er .
DLD-1	III	88
Colo 205	V	

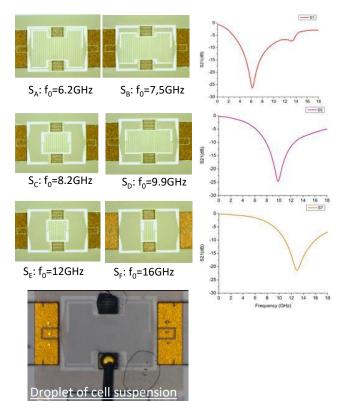
Dielectric signature established using Microwave resonating sensors









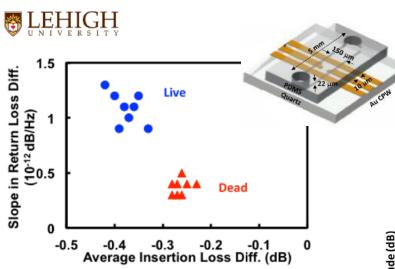


L.Y. Zhang et al, Discrimination of Colorectal Cancer Cell Lines using Microwave Biosensors Sensors & Actuators: A. Physical, Vol 216, Sept 2014.

Dielectric spectroscopy on living cells: measurement inside a liquid



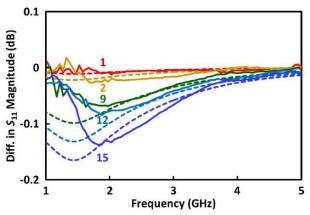
Probing living cells required sensors embedded in microfluidic channels

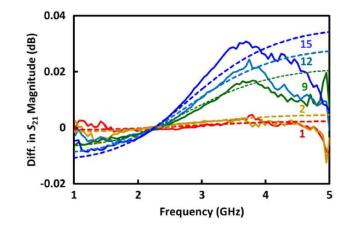


H. Li et al, DOI: 10.1109/TMTT.2017.2659736

Measuring dielctric property of small particles suspended in liquid involved several challenges:

- Measurement accuracy and stability
- Choice of probing frequency
- Single cell measurement
- Requirement to be associated with cell trapping (especially for broadband meas)

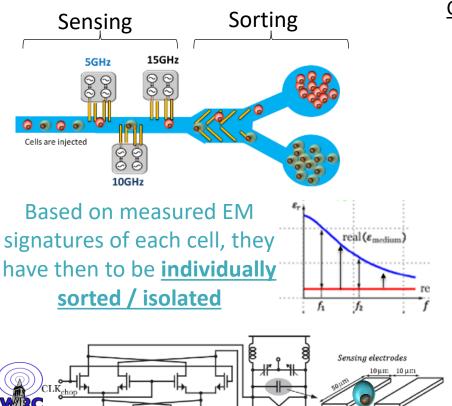




Toward to a dielectric spectroscopy cytometer concept

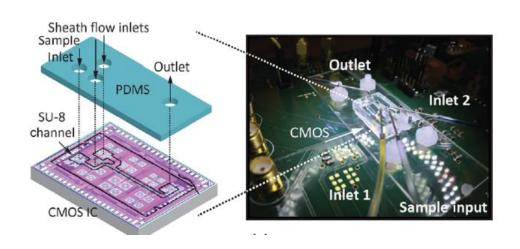


Potentially High-Throughput flowing cells microwave characterization



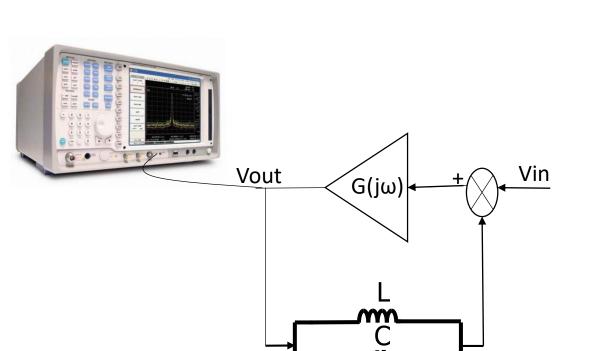
Challenges:

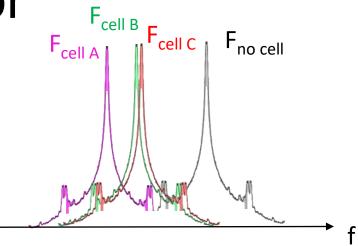
- -Require strong sensitivity (ppm range!) sensor design with **attoF resolution** \implies A cell in liquid $\sim 100-200 \text{ aF}$
- Need to be associated with cell sorting system



J.C.Chien et al, DOI: 10.1109/JSSC.2015.2500362

From resonator to oscillator





No cell vs one

single cell

Cancerous cell
vs another one
with tumor grade difference

THE ART OF MICROWAVES

Estimated capacitance 200 95 31 10 3 change (attoF) Induced frequency 500 300 100 32 10 shift (kHz)



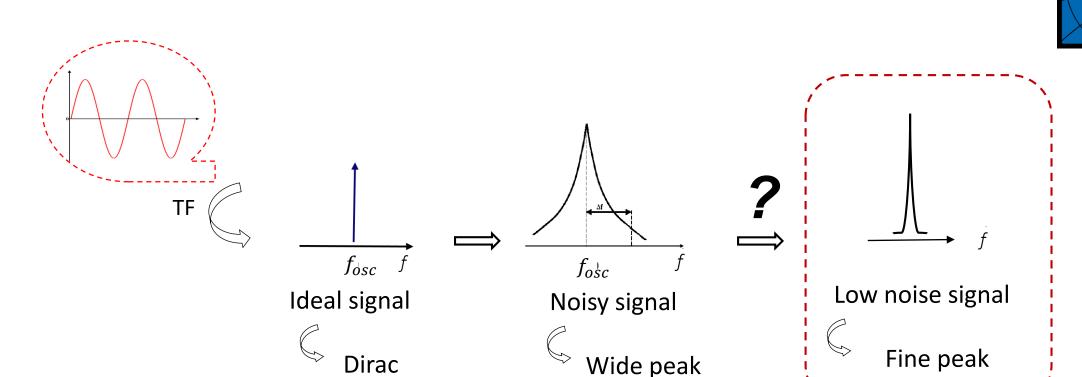
Oscillator based sensor might be more prone to detect such limited capacitance change

Ccell

Cancerous cell vs a different type one

Ex: Healthy vs cancerous cells

Oscillator based sensor's major requirement



✓ Stability of the oscillation frequency

✓ Spectral purity of the oscillator

Objective: Detect 10 kHz frequency shift around 5 GHz

Principle of an Injection Locked Oscillator

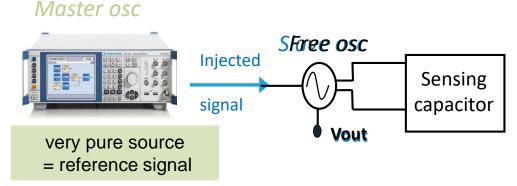


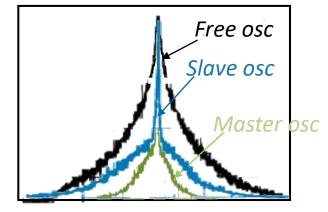
Capacitive sensor with very high sensitivity



Injection Locked Oscillator

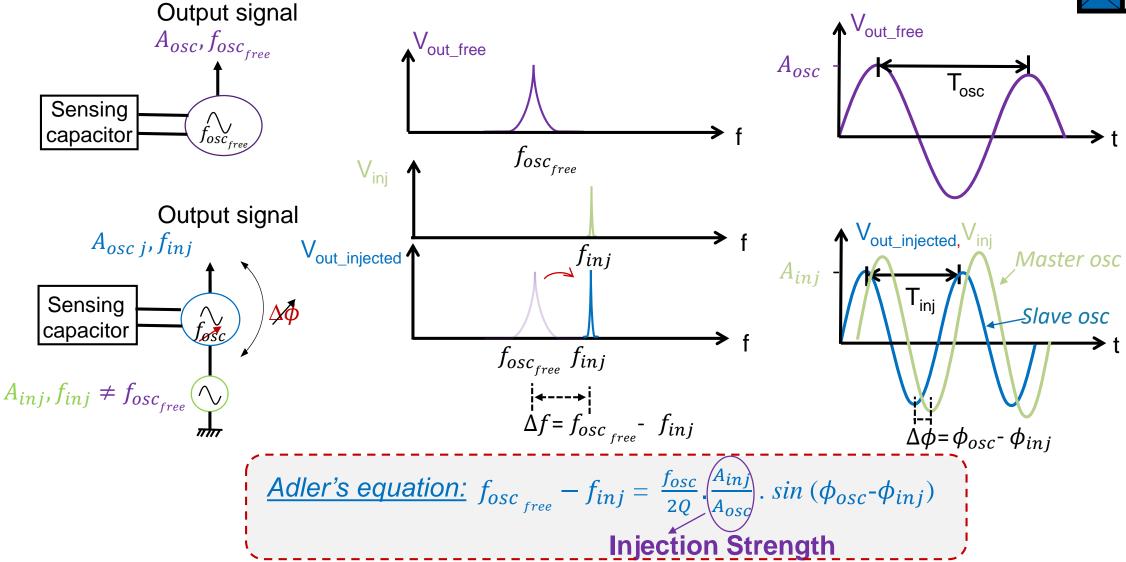
Principle: Reduce phase noise near the carrier



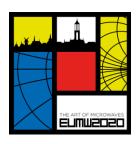


Principle of an Injection Locked Oscillator





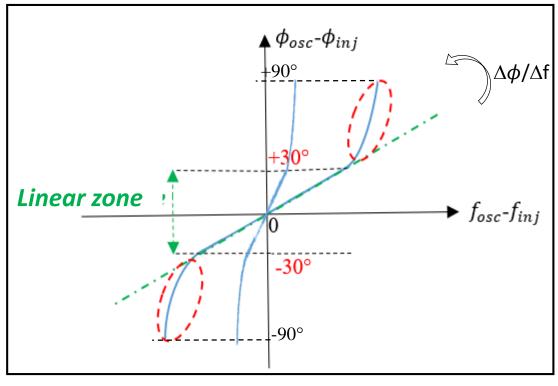
How using Injection Locked Oscillator as sensor?



- Lock / synchronize the master / slave oscillators
- ✓ Lower the injection strength / the injection amplitude of the master oscillator
 - Increase the slope $\Delta \phi / \Delta f$:

Improve the sensitivity of the sensor

Significant phase shift



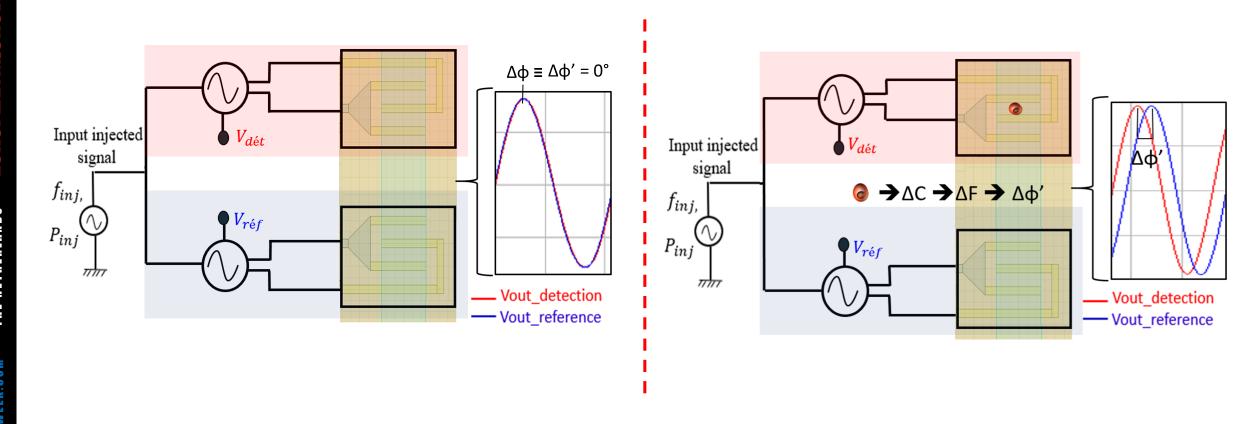
> Adapt the injection strength to get the required level of sensibility | Work in low injection regime



Sensing system architecture



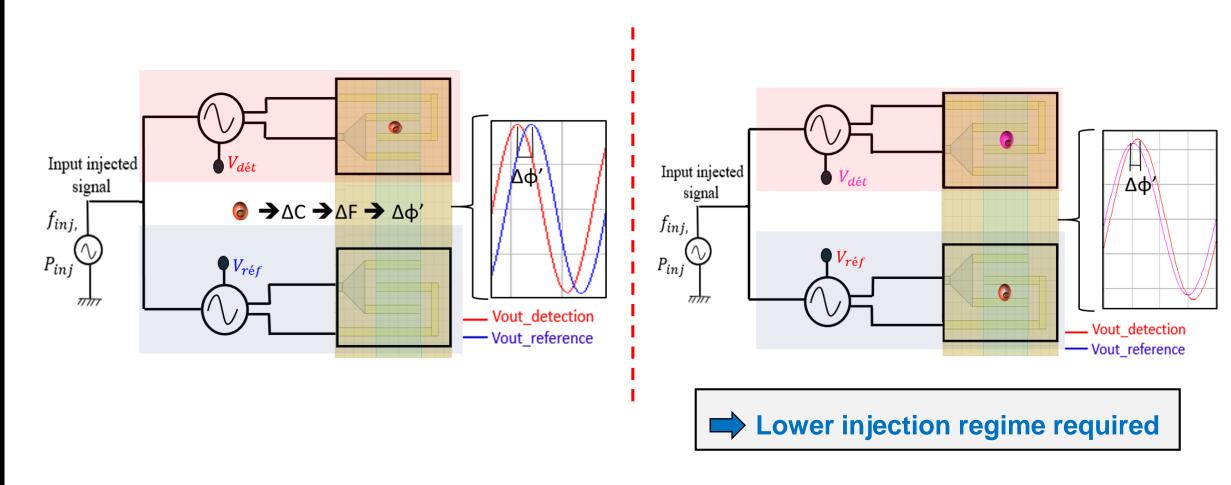
Two successive ILOs to enable differential measurement



Sensing system architecture

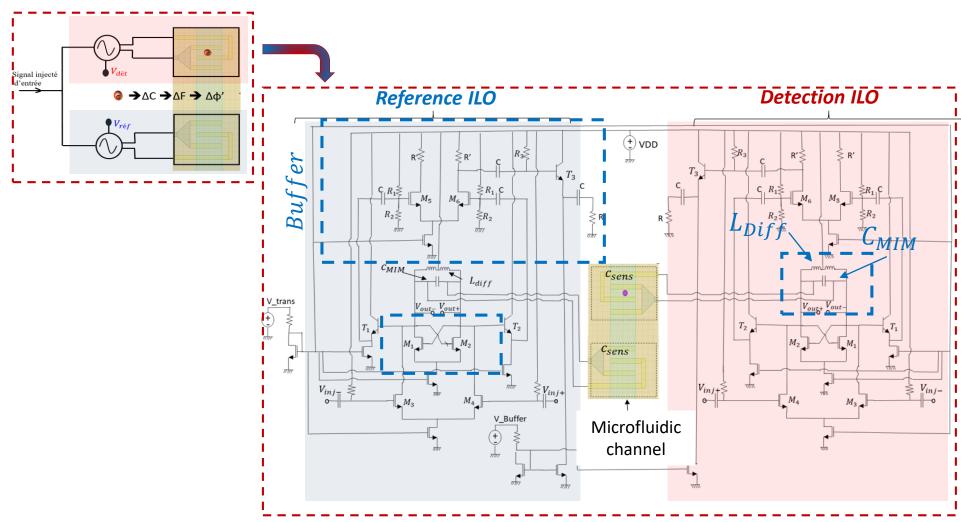


Two successive ILOs to enable differential measurement



Design of the sensing system

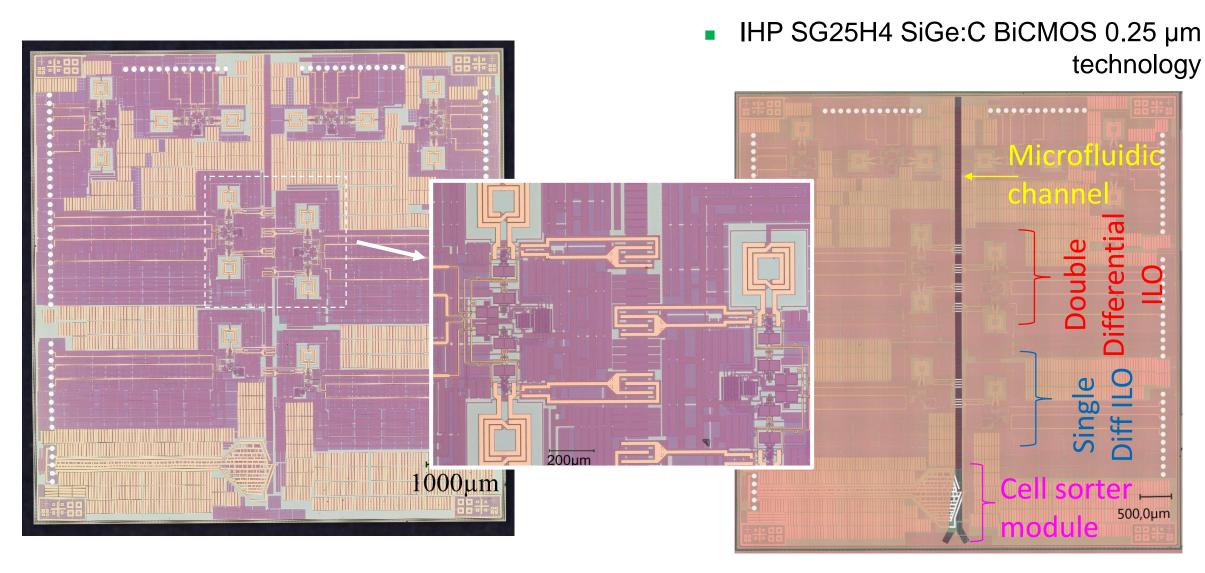




Fabricated chip photo

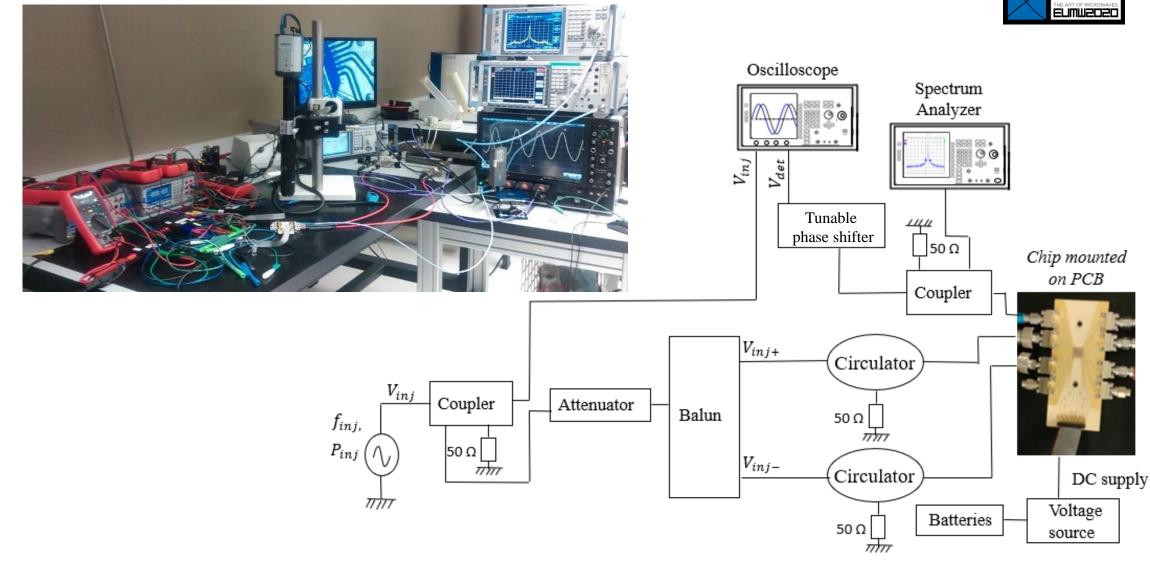


• Chip size: 7x 7 mm²



Measurement setup



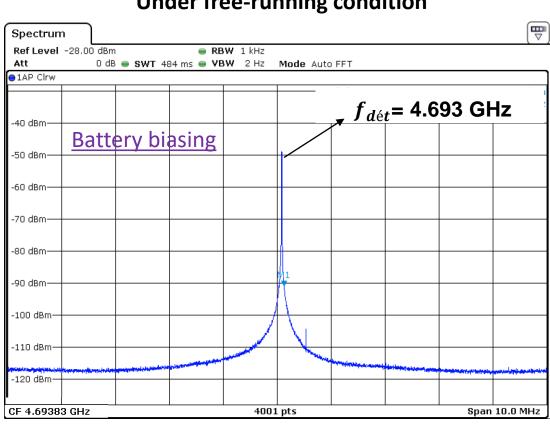


Measured output spectra

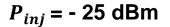


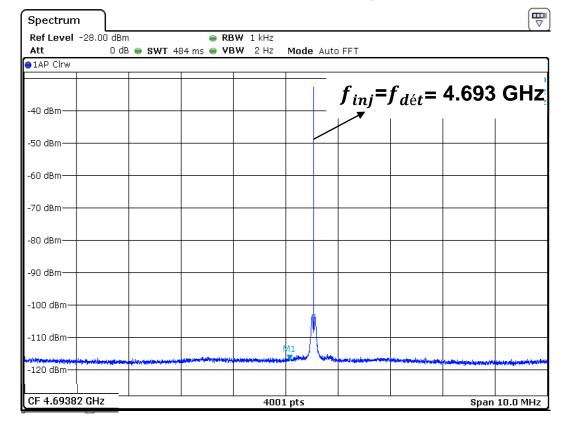
Output spectrum of the sensing oscillator

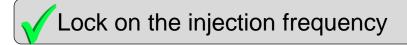
Under free-running condition



Under locked condition:









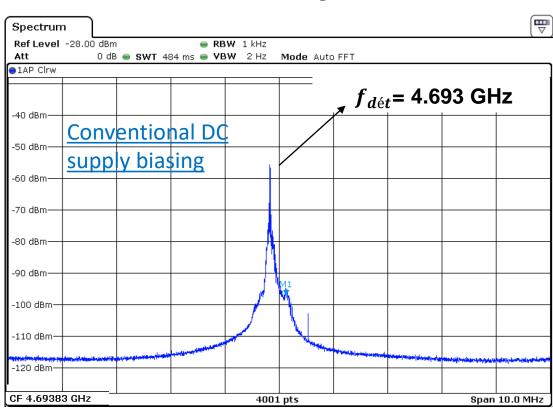
Phase noise is reduced near the carrier

Measured output spectra

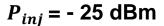


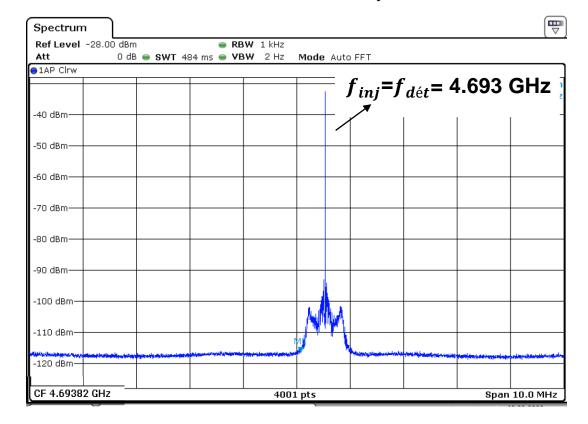
Output spectrum of the sensing oscillator

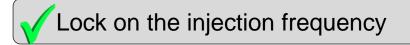
Under free-running condition



Under locked condition:







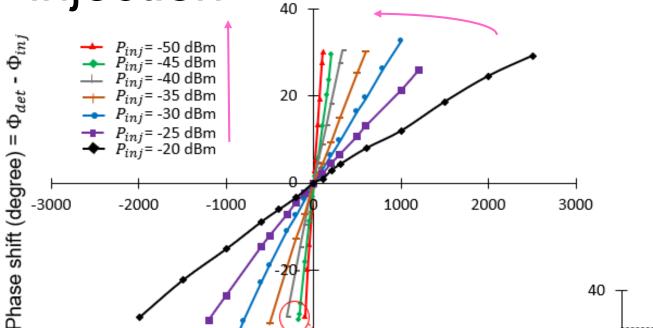


Phase noise is reduced near the carrier

Sensing oscillator locked by

injection

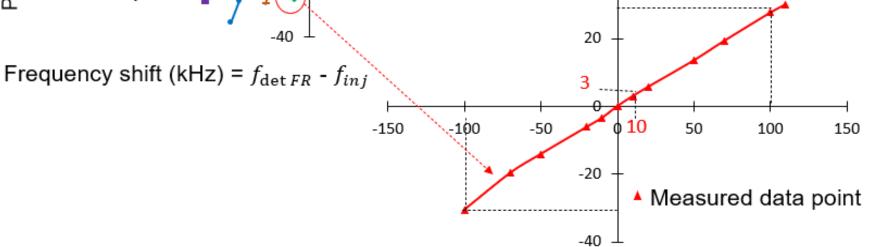




- $\checkmark f_{det} = f_{ref} = 4.693 \text{ GHz}$
- $\checkmark P_{inj} = -50 \text{ dBm}$



ightharpoonup Detection of $\Delta f = 10$ kHz around the operation frequency 4.693 GHz



Sensing oscillator locked by injection



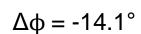
- ✓ P_{inj} =-50 dBm
- ✓ $f_{inj} = 4.693 \text{ GHz}$

$$\Delta f$$
= -100 kHz

$$\Delta \varphi = -31.6^{\circ}$$







10 mV

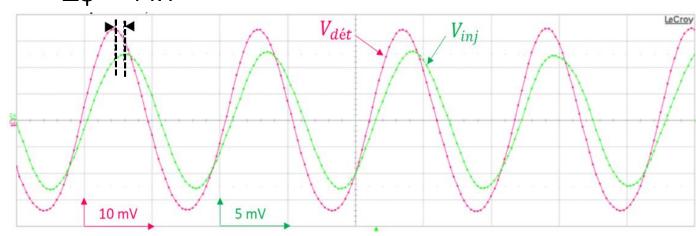
 $\Delta \phi = -31.6^{\circ}_{Slave\ detection\ osc}$

5 mV

$$\Delta f = -40 \text{ kHz}$$

$$\Delta \varphi = -14.1^{\circ}$$





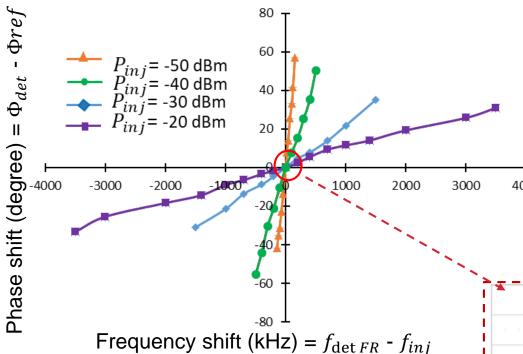
 $V_{d\acute{e}t}$

Master osc

 V_{inj}

Measured phase shift between ILO

outputs



Without any dielectric disturbance on

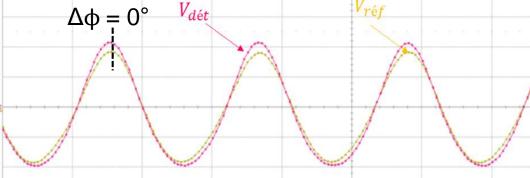
the detection oscillator

No frequency shift Δf

Phase shift $\Delta \phi = \Phi_{det FR} - \Phi_{inj} = 0^{\circ}$

Slave detection osc

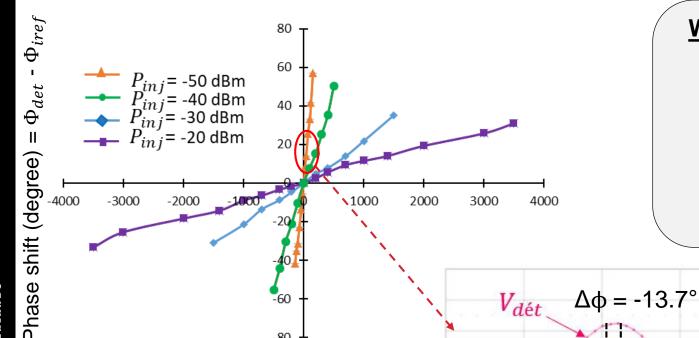
Slave reference osc



- ✓ P_{inj} =-50 dBm
- ✓ $f_{inj} = f_{ref} = f_{det} = 4.693 \text{ GHz}$

Measured phase shift between ILO outputs



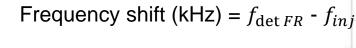


When dielectric perturbation occurs

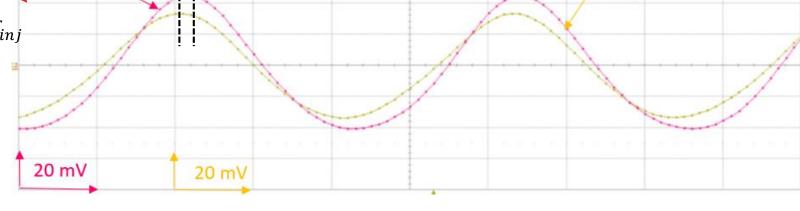
on the detection oscillator

Frequency shift $\Delta f = +40 \text{ kHz}$

Phase shift $\Delta \phi = -13.7^{\circ}$



- ✓ P_{inj} =-50 dBm
- ✓ $f_{inj} = f_{ref} = 4.693 \text{ GHz}$

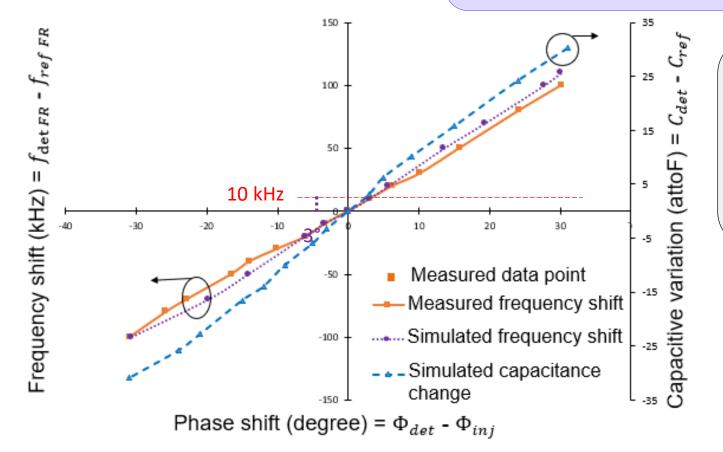


Measured phase shift between ILO outputs



- $\checkmark P_{inj}$ =-50 dBm
- ✓ $f_{inj} = f_{réf} = 4.693 \text{ GHz}$

❖ Differential measurement of the free running frequency change between detector and reference ILOs according to the measured phase shift between both output signals



- ✓ **ΔC = 3 aF** around <u>670 fF</u> of the overall LC tank capacitor
- $\checkmark \Delta f = 10 \text{ kHz}$ around 4.693 GHz
- ✓ Detected phase shift $\Delta \phi = 3^{\circ}$

Capacitive sensing sensitivity



5 ppm

Conclusion



- ✓ Implementation of an ultra-sensitive capacitive sensor based on an injection-locked oscillator architecture on a BiCMOS SiGe 0.25µm technology,.
- ✓ The detection system is able to detect <u>capacitance changes in the range of few attoF</u>, induced by <u>dielectric disturbance</u> occurring on on-chip integrated sensing capacitors.
- ✓ Measurement results show that such an architecture is able to achieve <u>5 ppm</u> sensing sensibility.
- ✓ Such detection level are especially required for future lab-on-chip development for biomedical diagnosis purpose.



Thank you for your attention



This project has received funding from the European Union's Horizon 2020 research and innovation program under grant agreement N° 737164

